



EPPL COMPONENT

Originator: null

Status: CLOSED

Company: UMS

Accepted: 2011-08-04

EPPL Part: 2

Group: MICROCIRCUITS Subgroup: MICROWAVE MONOLITIC
INTEGRATED CIRCUITS
(MMIC)

Part type:

PH25

Description: MMIC GaAs Foundry Process, 0.25 um Pseudomorphic High Electron Mobility Transistor (P-HEMT) for low noise, low level applications up to 100 GHz

Detail spec:

Package: N/A

Manufacturer: UMS

APPROVAL STATUS

Qualification: Others

Other:

Highest screening level (MIL): NO QUALIFICATION

Evaluation programmes or other approvals:

Former space usage:

PREVIOUS PROCUREMENT AND TEST DATA

Test data (Evaluation, Lot acceptance, DPA, MIL QCI/TCI, ...):

RADIATION HARDNESS DATA

Total dose effects:

Displacement damage:

Single event effects (SEL/SEU/SET/SEFI/SEB/SEGR/others):

REMARKS